Schottky Barrier Diode

NSR0530H

Schottky barrier diodes are optimized for very low forward voltage drop and low leakage current and are used in a wide range of dc-dc converter, clamping and protection applications in portable devices. NSR0530H in a SOD-323 miniature package enables designers to meet the challenging task of achieving higher efficiency and meeting reduced space requirements.

Features

- Very Low Forward Voltage Drop 370 mV @ 100 mA
- Low Reverse Current 1.4 μA @ 10 V VR
- 500 mA of Continuous Forward Current
- Very High Switching Speed
- Low Capacitance CT = 10 pF
- This is a Pb-Free Device

Typical Applications

- LCD and Keypad Backlighting
- Camera Photo Flash
- Buck and Boost dc-dc Converters
- Reverse Voltage and Current Protection
- Clamping & Protection

Markets

- Mobile Handsets
- MP3 Players
- Digital Camera and Camcorders
- Notebook PCs & PDAs
- GPS

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Reverse Voltage	V _R	30	V
Forward Current (DC)	ΙF	500	mA
Forward Surge Current (60 Hz @ 1 cycle)	I _{FSM}	2.5	Α
ESD Rating: Human Body Model Machine Model	ESD	Class 3B Class C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1

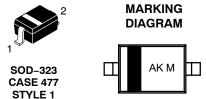


ON Semiconductor®

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30 V SCHOTTKY BARRIER DIODE





AK = Specific Device Code M = Month Code

ORDERING INFORMATION

Device	Package	Shipping†
NSR0530HT1G	SOD-323 (Pb-Free)	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NSR0530H

THERMAL CHARACTERISTICS

Characteristic	Symbol	Min	Тур	Max	Unit
Thermal Resistance Junction-to-Ambient (Note 1) Total Power Dissipation @ T _A = 25°C	R _{θJA} P _D			740 160	°C/W mW
Thermal Resistance Junction-to-Ambient (Note 2) Total Power Dissipation @ T _A = 25°C	R _{θJA} P _D			460 270	°C/W mW
Junction and Storage Temperature Range	T _J , T _{stg}			-55 to +150	°C

- Mounted onto a 4 in square FR-4 board 10 mm sq. 1 oz. Cu 0.06" thick single sided. Operating to steady state.
 Mounted onto a 4 in square FR-4 board 1 in sq. 1 oz. Cu 0.06" thick single sided. Operating to steady state.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Leakage (V _R = 10 V) (V _R = 30 V)	I _R		1.4 24	10 200	μΑ
Forward Voltage (I _F = 10 mA) (I _F = 100 mA) (I _F = 500 mA)	V _F		0.28 0.37 0.52	0.37 0.46 0.62	٧
Total Capacitance (V _R = 1.0 V, f = 1 MHz)	СТ		10		pF

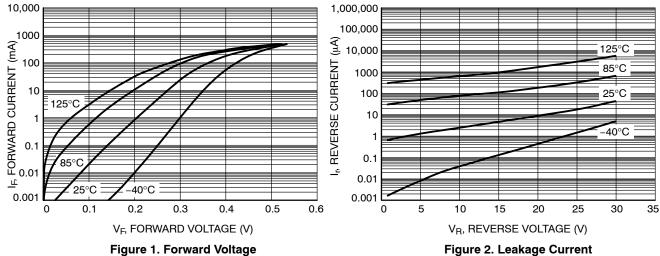


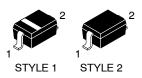
Figure 1. Forward Voltage

20 18 $T_A = 25^{\circ}C$ C_T, TOTAL CAPACITANCE (pF) 16 14 12 10 8 6 4 2 0 0 5 10 15 20 30 35 V_R, REVERSE VOLTAGE (V)

I_{FSM}, FORWARD SURGE CURRENT (A) Based on square wave currents T_J = 25°C prior to surge 3.5 2.5 1.5 0.5 0 0.001 0.01 0.1 100 1000 T_P, PULSE ON TIME (ms)

Figure 3. Total Capacitance

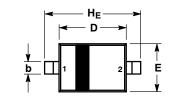
Figure 4. Forward Surge Current

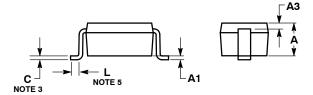


SOD-323 CASE 477-02 **ISSUE H**

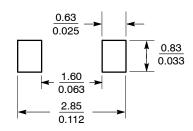
DATE 13 MAR 2007

SCALE 4:1





SOLDERING FOOTPRINT*



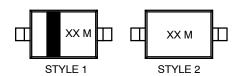
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NOTES:

- VIES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETERS.
- 3. LEAD THICKNESS SPECIFIED PER L/F DRAWING WITH SOLDER PLATING.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD
- FLASH, PROTRUSIONS OR GATE BURRS.
 5. DIMENSION L IS MEASURED FROM END OF RADIUS.

	MILLIMETERS				INCHES			
DIN	MIN	NOM	MAX	MIN	NOM	MAX		
Α	0.80	0.90	1.00	0.031	0.035	0.040		
A1	0.00	0.05	0.10	0.000 0.002		0.004		
A3	0.15 REF 0.006 REF			F				
b	0.25	0.32	0.4	0.010	0.012	0.016		
С	0.089	0.12	0.177	0.003	0.005	0.007		
D	1.60	1.70	1.80	0.062	0.066	0.070		
Е	1.15	1.25	1.35	0.045	0.049	0.053		
L	0.08			0.003				
HE	2.30	2.50	2.70	0.090	0.098	0.105		

GENERIC MARKING DIAGRAM*



XX = Specific Device Code M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

PIN 1. CATHODE (POLARITY BAND) 2. ANODE

NO POLARITY

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SK32A-LTP SK34B-TP SS3003CH-TL-E GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBRB30H30CT-1G SB007-03C-TB-E SK32A-TP SK33B-TP SK38B-TP NRVBM120LT1G NTE505 NTSB30U100CT-1G SS15E-TP VS-6CWQ10FNHM3 ACDBA1100LR-HF ACDBA1200-HF ACDBA2100-HF ACDBA3100-HF CDBQC0530L-HF ACDBA340-HF ACDBA260LR-HF

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